NSN 5961-01-433-1682

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-433-1682 **Inclosure Material:** Plastic **Overall Length:** 0.250 inches **Overall Height:** 0.055 inches **Overall Width:** Between 0.092 inches and 0.104 inches **Mounting Facility Quantity: Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon alloy **Voltage Rating In Volts Per Characteristic:** 30.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 07187-8521485 manufacturers source control Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0